

Product data sheet

1. General description

Planar passivated four quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance.

2. Features and benefits

- High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- · Less sensitive gate for high noise immunity
- Triggering in all four quadrants

3. Applications

- General purpose motor controls
- General purpose switching

4. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|--|---|-----|-----|-----|------|
| V _{DRM} | repetitive peak off- state voltage | | - | - | 600 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \frac{\text{Fig. 4}}{25}; \frac{1}{25}; \frac{1}{2$ | - | - | 155 | A |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 99 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3 | - | - | 16 | A |
| Static char | acteristics | ` | | | | , |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 7}}{2}$ | - | 5 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 8 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 10 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 22 | 70 | mA |





5. Pinning information

| Table 2. | Table 2. Pinning information | | | | | | | |
|----------|------------------------------|-----------------------------------|--------------------|----------------|--|--|--|--|
| Pin | Symbol | Description | Simplified outline | Graphic symbol | | | | |
| 1 | T1 | main terminal 1 | mb | T2 | | | | |
| 2 | T2 | main terminal 2 | | sym051 | | | | |
| 3 | G | gate | | | | | | |
| mb | Τ2 | mounting base; main terminal 2 | | | | | | |
| | | | TO-220AB (SOT78) | | | | | |

6. Ordering information

| Table 3. Ordering information | | | | | | |
|-------------------------------|----------|--|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| BT139-600 | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 | | | |

7. Limiting values

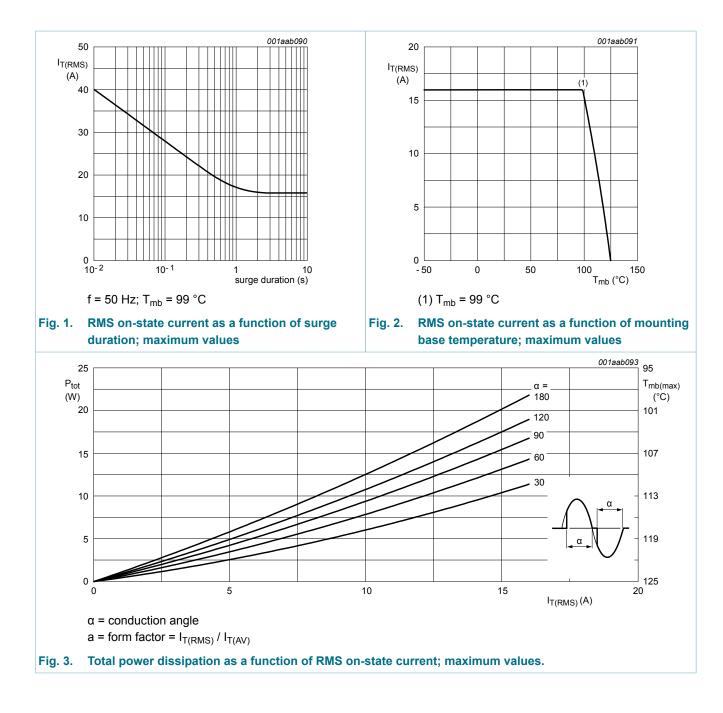
Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 99$ °C; Fig. 1; Fig. 2; Fig. 3 | - | 16 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; Fig. 4; Fig. 5$ | - | 155 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 170 | A |
| l ² t | I2t for fusing | t _p = 10 ms; SIN | - | 120 | A ² s |
| dl _T /dt | rate of rise of on-state current | I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2+ G+ | - | 50 | A/µs |
| | | I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2+ G- | - | 50 | A/µs |
| | | I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2- G- | - | 50 | A/µs |
| | | I_T = 20 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2- G+ | - | 10 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |

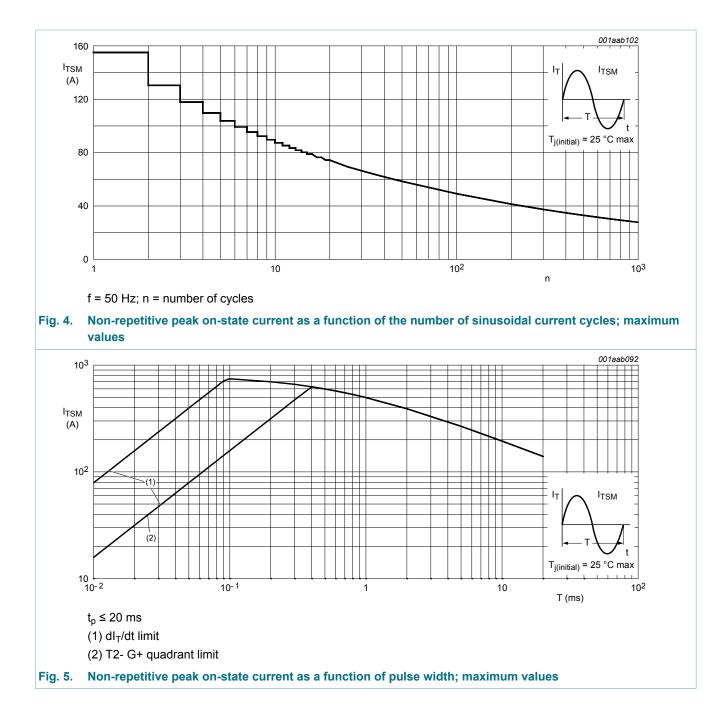
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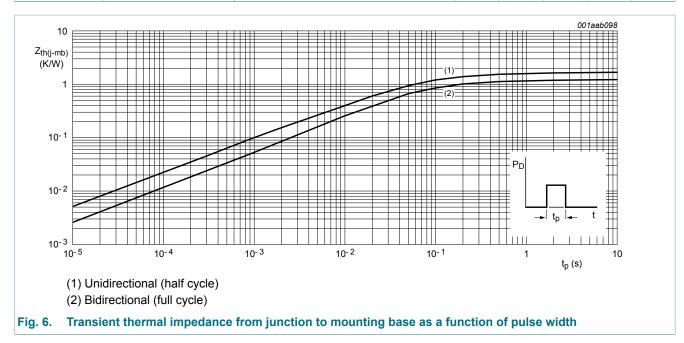
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8. Thermal characteristics

| Table 5. T | hermal characteristics | | | | | |
|-----------------------|---|---------------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-mb)} | thermal resistance | half cycle; <u>Fig. 6</u> | - | - | 1.7 | K/W |
| | from junction to mounting base | full cycle; <u>Fig. 6</u> | - | - | 1.2 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |

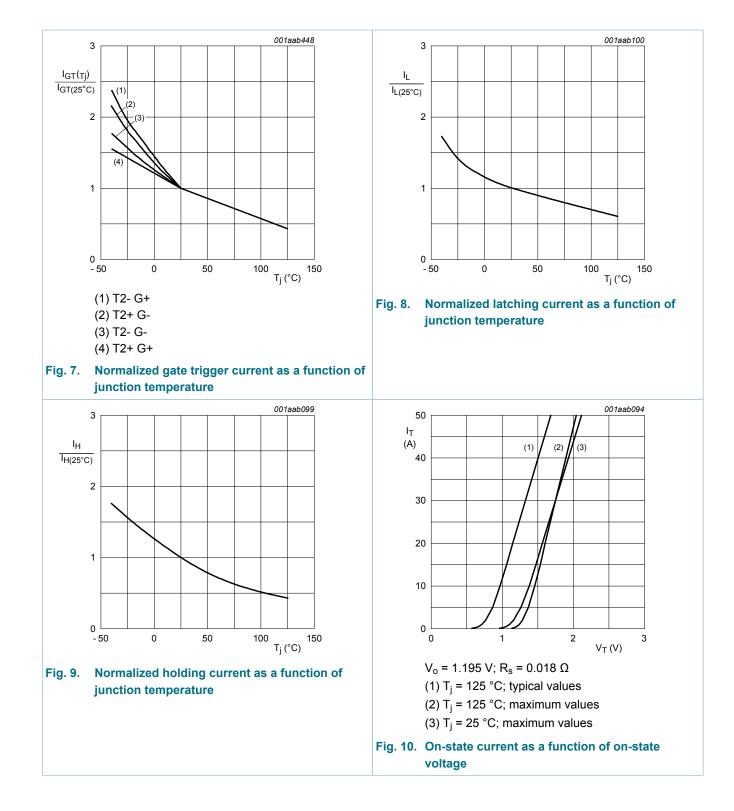


9. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|------|-----|-----|------|
| Static chara | octeristics | I I | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 8 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 10 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 22 | 70 | mA |
| ΙL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | 7 | 40 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 8</u> | - | 20 | 60 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 8 | - | 8 | 40 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; Fig. 8 | - | 10 | 60 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 6 | 45 | mA |
| V _T | on-state voltage | I _T = 20 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.2 | 1.6 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| l _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic ch | aracteristics | · · · · · · · · · · · · · · · · · · · | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 200 | 250 | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | V_D = 400 V; T _j = 95 °C; dI _{com} /dt = 7.2 A/ ms; I _T = 16 A; gate open circuit | 10 | 20 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | I_{TM} = 20 A; V _D = 600 V; I _G = 0.1 A; dI _G / dt = 5 A/µs | - | 2 | - | μs |

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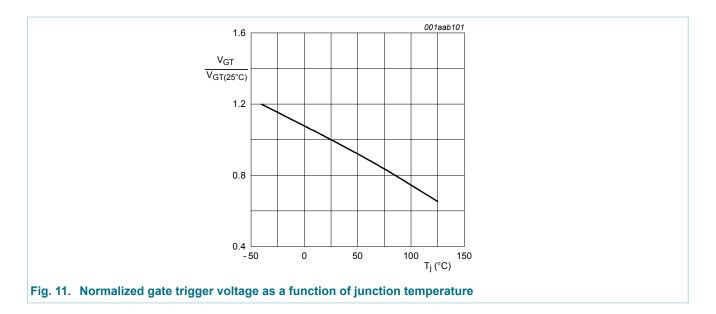


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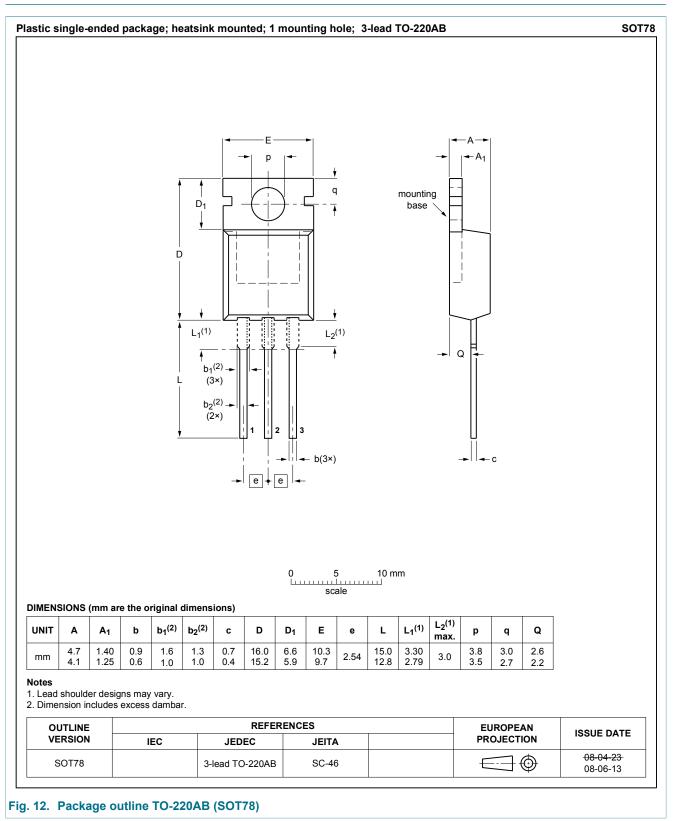
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10. Package outline



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|--------------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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